NSN 5961-01-262-6053

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-262-6053 **Inclosure Material:** Glass **Overall Length:** 0.300 inches **Terminal Length:** 0.975 inches **Overall Diameter:** 0.145 inches **Mounting Method: Terminal Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 400.0 reverse voltage, peak **Current Rating Per Characteristic:** 3.00 amperes forward current, average absolute and 70.00 amperes forward current, average preset **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Nuclear Hardness Critical Feature:** Hardened **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No